## A nharm onic e ects in the A 15 com pounds induced by sublattice distortions

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W e demonstrate that elastic anom alies and lattice instabilities in the the A15 compounds are describable in terms of rst-principles LDA electronic structure calculations. W e show that at T = 0 V<sub>3</sub>Si, V<sub>3</sub>Ge, and Nb<sub>3</sub>Sn are intrinsically unstable against shears with elastic moduli C<sub>11</sub> C<sub>12</sub> and C<sub>44</sub>, and that the zone center phonons, <sub>2</sub> and <sub>12</sub>, are either unstable or extremely soft. W e demonstrate that sublattice relaxation (internal strain) e ects are key to understanding the behavior of the A15 m aterials.

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The A15 m aterials have been of interest form ore than 40 years due to the relatively high superconducting transition temperatures for many of them and the interplay between their superconductivity, their structural phase transitions, and their tem perature-dependent anom alies in properties such as elastic constants, phonon spectra, electrical resistivity, K night shift and m agnetic susceptibility. [1{3] The paradigm interesting A 15 m aterials are  $V_3$ Si and Nb<sub>3</sub>Sn, both of which have relatively high  $T_c$ values and also undergo cubic-to-tetragonal structural phase transitions just above  $T_c$  (with  $\frac{c}{a} > 1$  and  $\frac{c}{a} < 1$ , respectively), and have many other anom alous properties as well. M any theoretical models, discussed in Refs. [1-3], attempt to explain the unusual properties of the A 15 m aterials in terms of m odels with a sharply peaked structure in the electronic density of states (DOS) near the Ferm i level,  $E_F$ .

A lthough the past ten years has seen a major focus on developing an understanding of the ceram ic oxide superconductors, [4] there remain many unanswered fundam ental questions related to the unusual properties of the A 15 m aterials, including the question of the relationship between their high  $T_c$  and their structural anom alies/instabilities, and whether or not they are driven directly by the electronic distribution using a conventional Ferm i liquid description of the electronic structure, or whether \exotic" excitations are needed to explain the properties. Some of these issues may have relevance to the high  $T_c$  oxides as well, where structural instabilities are also known to exist. [4]

Here we show that using state-of-the-art rst-principles electronic structure methods to study three of the most interesting A 15 m aterials:  $V_3Si$ ,  $Nb_3Sn$ , and  $V_3Ge$ . We have found several provocative results, including the facts that: (1) for all three materials the calculated elastic constants agree very well with the observed room temperature values if sublattice relaxation elects are frozen out; (2) when sub-lattice relaxation elects are included, the crystals are unstable in the cubic A 15 structure with respect to a tetragonal distortion which stabilizes both the elastic constants and the phonon anom alies; (3) the structural instability is weakest (in terms of the energetics) in  $V_{3}G$  e and m ay not be observable due to e ects of crystal in perfections; (4) anom alies in several of the zone-center phonon branches occur along with the elastic anom alies, the branches corresponding to m odes where atom s in the chains vibrate in the chain direction.

The electronic structure results reported in this Letter were generated using the all-electron, full-potential linearized-augmented-plane-wave (LAPW) method in the local density approximation (LDA). The valence/conduction band states were treated semirelativistically (no spin-orbit e ects) while the core states were treated fully relativistically. Care was taken to ensure appropriate k-point convergence for the accuracy needed in these studies.

U sually it is found that the elastic constants, when evaluated at the experimental volume, are within 5–10% of the experimental values. [5] For a cubic system (such as the A 15) to be mechanically stable, the bulk modulus (B  $\frac{C_{11}+2C_{12}}{3}$ ) and shear elastic constants (C<sub>11</sub> C<sub>12</sub> and C<sub>44</sub>) must be positive. The overall phonon spectrum must be stable as well (positive square frequencies). The elastic constants can be extracted using the procedures discussed by M ehlet al.: [5] (i) calculate the total energy as a function of the volume, and then t the results to an equation-of-state to extract the bulk modulus B;

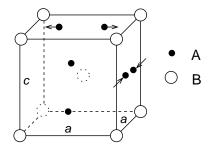


FIG.1. Schematic diagram of ideal (c = a) and tetragonally distorted (c  $\epsilon$  a) A15 crystal structures (A<sub>6</sub>B<sub>2</sub>). B atoms form a body-centered cube, while A atoms form linear chains on each cube face. A rrows denote allowed internal degrees of freedom (direction of sublattice relaxations) in the tetragonally distorted A15 structure.

(ii) apply an appropriate strain to the lattice to distort the primitive lattice vectors, calculate the total energy versus strain at volum eV, and determ ine the secondorder elastic constants from the coe cient second order in the strain. For example, using an orthorhom bic distortion, the distortion energy is,

We can thus extract  $C_{11}$   $C_{12}$  from Eq. (1). Similarly, we used a monoclinic distortion to extract  $C_{44}$ .

O ur calculated total energies of  $V_3Si$ ,  $V_3Ge$ , and  $Nb_3Sn$  in the A15 structure as a function of volum e, were used to extract the equilibrium volum es and bulk moduli of these materials. The calculated equilibrium volum es are underestim ated by 4-6%, typical of LDA calculations, leading to the calculated equilibrium bulk moduli being overestim ated com pared to experim ent by more than 25%. On the other hand, the calculated bulk moduli at the experim ental volum es are very close (5%) to those of experim ent, as shown in Table I.

Next, we exam ined the stability of the A15 m aterials under the application of shears corresponding to the elastic constants  $C_{11}$   $C_{12}$  and  $C_{44}$ , rst without allowing the cell-internal sublattice displacem ents that are allow ed by the broken sym m etries produced by the elastic distortions. Figure 2 depicts our calculated distortion energies (open squares) as a function of  $^2$  using orthorhom bically distorted cells. For a perfectly harm onic crystal, the data points would fall on a straight line, with the slopes given by  $C_{11}$   $C_{12}$ . Indeed the calculated points fall quite close to straight lines, indicating only sm all contributions from higher order term s [O ( $^4$ )]. The tted C<sub>11</sub> C<sub>12</sub> and C<sub>44</sub> values, shown in Table I, are very close to the experim ental room tem perature values, rather than to the low tem perature values as m ight be expected for a typical material. Since rst-principle calculations are supposed to correspond to T = 0, not to high tem peratures, why don't we reproduce the soft elastic constants seen at low tem perature?

This puzzle was solved by realizing that as one distorts a crystal from a higher to a lower sym metry space group, new internal degrees of freedom could be introduced with signi cant physical and computational importance, especially for system s with lattice instabilities. We note that it is tempting to overlook these sublattice distortions because determ ining their e ect introduces a large increase in the computational burden, since for each internal distortion a set of self-consistent calculations needs to be performed to nd the equilibrium sublattice distortions corresponding to the volum e and strain under investigation.

For the orthorhom bically distorted A 15 cell, the sublattice displacements correspond to pairs of A atoms m oving toward or away from each other (rather than xing on their symmetry m and ated A 15 positions), but

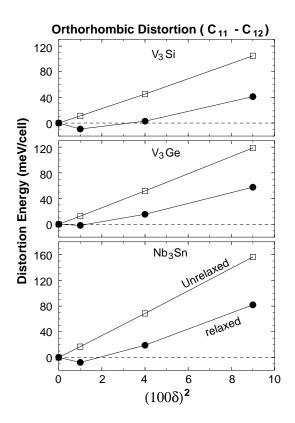


FIG.2. D istortion energies for orthorhom bically distorted A15 structure. Calculations were performed at the experimental A15 volumes. The open squares denote calculation performed with A15-like internal coordinates, while led circles denote calculations with internal coordinates fully relaxed.

di erent pairs move independently. Thus, we need to add (iii) sublattice relaxation into our above procedures for calculating elastic constants. A fier fully relaxing the sublattices, we have found that the relaxed distortion energies for the A15 compounds (denoted by lled circles in Figure 2) are lowered by a substantial am ount, which increases as the distortion gets larger. The relaxed distortion energies show a m inim um around  $1\{2\%$  and even dip below the energies of the \ideal" cubic A15 structure. Hence, these three A15 compounds are intrinsically unstable in the cubic structure at T = 0. Note that the  $C_{11}$   $C_{12}$  instability appears to be weakest in  $V_3G$  e. Again, the weakest  $C_{44}$  instability occurs in  $V_3G$  e, while the strongest instability occurs for N b<sub>3</sub>Sn, as seen in experiment (Table I).

An alternative way to obtain  $C_{11}$   $C_{12}$  is to distort the cell tetragonally. This tetragonally distorted cell turns out to have the same structure as the observed tetragonal phase [6] for some A 15 compounds (Fig. 1). The distortion energies are depicted as a function of distortion ( $=\frac{c}{a}$  1) in Fig. 3. If we freeze the atom s in their A 15-like coordinates, the calculated sublattice-unrelaxed distortion energies (denoted by open squares) fall quite closely on a parabola. Note that the distortion energy

contains odd term s of distortion  $=\frac{c}{a}$  1 rather than being an even function of as in the case of orthorhom – bic and m onoclinic distortions, so that we needed to perform m ore rst-principles calculations (for ) for this case. Indeed, we see a slight asymmetry about the = 0 axis, indicating a small cubic term [D (<sup>3</sup>)]. Least-square

tting these data to the form a  $^2$  + b  $^3$  + c  $^4$ , we can extract  $C_{11}$   $C_{12}$  = 3a=V. Such tted  $C_{11}$   $C_{12}$  values are within 6% of those shown in Table I using orthorhom bically distorted cells.

Next we allowed the internal coordinates to relax in a manner consistent with the tetragonal structure, and found that the distortion energies were low ered by a large am ount, showing a double well structure with respect to  $\frac{c}{2}$ . In the case of V<sub>3</sub>Si, the minimum occurs for  $\frac{c}{2} > 1$ , while for Nb<sub>3</sub>Sn the minimum occurs for  $\frac{c}{2} < 1$ , in agreem ent with experim ental observations [1]. For the case of V<sub>3</sub>Ge, we nd an extremely shallow well and a much weaker instability (bordering on the accuracy of our LAPW calculations). Therefore, a sm all am ount of sample imperfection, such as impurities, vacancies, or disorder, or thermal e ects, could inhibit the transition from occurring in V<sub>3</sub>Ge. Experimentally, no cubic-totetragonal phase transition has been observed for  $V_3Ge_{I}$ although there is som e evidence for anom alies in its elastic constants [7].

ForV<sub>3</sub>Siand Nb<sub>3</sub>Sn, the details of the structural phase transitions are very sensitive functions of sam ple conditions, with, for instance, the observed  $\frac{c}{a}$  ratios, varying from 0.9964 to 0.9938 for Nb<sub>3</sub>Sn and approximately 1.0024 forV<sub>3</sub>Si, [1], while the calculated minimum occurs at  $\frac{c}{a}$  about 1.02 and 0.985 for V<sub>3</sub>Si and Nb<sub>3</sub>Sn, respectively, signi cantly larger than experiment. Since the relaxed distortion energy curves are very small and the curves are very at, a precise determination of the  $\frac{c}{a}$  ratio is di cult, although m ost of the quantitative disagreement between theory and experiment can be ascribed to LDA errors that do not a ect the conclusions regarding the instabilities that we are focusing on.

W e see from these results that the key to understanding the elastic constant softening, and most probably other anom alous properties in the A15 m aterials, is the relaxation of the internal degrees of freedom (sublattice relaxation) when there are cell distortions, which leads to highly anham onic behavior in the A15's, general ideas put forward by Testardi. [8] At high tem peratures, therm almotion washes away the well structure and atom s spend the majority of their time away from the at well m in in a and assume \average" A 15 positions. Calculations with \frozen-in" A 15-like coordinates give the maximum attainable elastic constants, which correspond closely to the experim ental room tem perature values. As the tem perature is lowered, the e ect of sublattice relaxation sets in, and at T = 0, these A15 compounds are intrinsically unstable with respect to C  $_{11}$   $\,$  C  $_{12}$  and C<sub>44</sub> shear distortions. These results can be interpreted

in term s of a ferroelastic type of instability as discussed by M iller and A xe [13], with examples given in the book of Silje. [14]

We have seen that the rst-principles electronic structure m ethod predicts the existence of elastic constant instabilities and the cubic to tetragonal phase transition in A 15 m aterials. It is also well established that the overall phonon spectra of many of the A15's exhibits unusual tem perature dependencies and selected softening in different parts of the Brillouin Zone [6,9,10]. Such instabilities for the phonons also follow from our calculations using the frozen phonon m ethod w hich we have applied to determ ine the zone-center optic phonons. Note that the relaxed distortion energy in Fig. 3 (c) for  $Nb_3Sn$  at = 0  $\left(\frac{c}{2} = 1\right)$  has a small negative value of 4 m eV /cell, indicating an unstable zone center 12 phonon, since this phonon has the same space group as the tetragonally distorted A15 cell, but with c a. The calculation for the 2 phonon (pairs of A atom s move toward or away from each other with the same displacements for all three orthogonal chains) also shows a small, negative phonon energy for Nb<sub>3</sub>Sn, indicating an instability. Calculations for the  $_{12}$  and  $_{2}$  phonons for V  $_{3}$ Si and V  $_{3}$ G e also show anom alies. However, for these materials these phonons have negative or very sm all positive energies, e.g., their phonon energies are less than 1 m eV /cell for the 12 phonon at a displacement of 0:003a, where a is the cubic lattice constant. For com parison, zone center phonon energies at the same displacem ent for a typical interm etallic compound such as  $Cu_3Pt$  in the cubic  $L1_2$ structure are 25 m eV /cell (where the unit cell contains

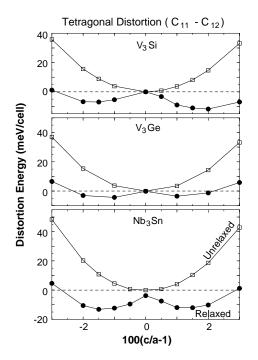


FIG.3. D istortion energies for tetragonally distorted A15 structure and also see captions of Fig.2.

4 atom s). Note that since we estimate the accuracy of ourLAPW calculations for phonon energies to be approximately 2 m eV/cell, we can argue that the zone center phonons  $_{12}$  and  $_{2}$  are extremely soft at best, and are on the borderline of being stable or unstable.

F irst-principles electronic structure calculations have shown that the DOS near  $E_F$  for  $V_3Si$  and Nb<sub>3</sub>Sn have very sharp structures, [11,12] in qualitative agreement with early model calculations of the DOS, and we nd similar results here. W hat is particularly interesting, how ever, is that we nd explicitly that the DOS singularities, and the associated Ferm i surface nesting features, are removed following the sublattice distortions and the resultant structural phase transitions. We will discuss this more fully in a future publication.

In sum m ary, it appears that m any of the unusual properties of the A15 m aterials are describable in terms of \standard" LDA electronic structure calculations when sublattice relaxation e ects are included. We have show n that the A15 m aterials ( $V_3$ Si,  $V_3$ Ge, and Nb<sub>3</sub>Sn) are intrinsically unstable against shears producing the m oduli  $C_{11}$   $C_{12}$  and  $C_{44}$ , at T = 0. Our calculations also indicate that the zone center phonons ( $_2$  and  $_{12}$ ) are either unstable or extrem ely soft at T = 0. Sim ilar studies of the full phonon spectrum and the superconducting tunneling functions for the A15 m aterials are being form ulated to verify whether the \standard" LDA m ethods are consistent with all of the experimental data.

As a word of caution, we urge that elastic stability of a  $\mod puter-designed$ " novel material should always be checked, as one would not have anticipated the calculated instabilities in the A 15 materials by exam ining the total energy verses volum e curves alone.

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TABLE I. LAPW calculated and experimental elastic constants (in GPa) (from Reference [1]). Calculations were performed at the experimental volume using orthorhom bic (for C<sub>11</sub> C<sub>12</sub>) and monoclinic (for C<sub>44</sub>) distorted cells. Unrelaxed" refers to calculations in which atom ic positions are held is their cubic, ideal sites, while \relaxed" refers to calculations in which sublattices are allowed to relax. The elastic constants were extracted from a least square it of distortion energies to the form :  $E = k_2^{-2} + k_4^{-4}$ . \Transforming" (\N on Transforming") denotes an experimental sample that undergoes (does not undergo) a cubic to tetragonal phase transition. The \unrelaxed" C<sub>11</sub> C<sub>12</sub> values can also be extracted using a tetragonal distortion: such extracted values are within 6% of those reported here.

	V <sub>3</sub> Si			V <sub>3</sub> Ge			Nb <sub>3</sub> Sn			
	Temp(K)	В	$\frac{C_{11} C_{12}}{2}$	C 44	В	$\frac{C_{11} C_{12}}{2}$	C 44	В	$\frac{\text{C}_{11}  \text{C}_{12}}{2}$	C 44
Calc. (Unrelaxed)	0	165	84	79	169	93	77	159	91	53
Expt. (Transform ing)	300	176	83.8	81.0			69.8	154	68	40.8
Expt. (Non Transform ing)	300	171	86	80.9	170	92	70.3	160	70.7	39.6
Calc. (Relaxed)	0	165	< 0	< 0	169	< 0	< 0	159	< 0	< 0
Expt. (Transform ing)	4.2	177	1.5	76.1			73.8	161	112	22.8
Expt. (N on Transform ing)	4.2	171	8	76.6	173	98.3	72.3	165	0	26.6